



FEATURES

- Double Side Cooling
- High Surge Capability

KEY PARAMETERS

V_{RRM}	5000V
$I_{F(AV)}$	3083A
I_{FSM}	55000A

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V_{RRM} V	Conditions
DRD3080V50	5000	$V_{RSM} = V_{RRM} + 100V$
DRD3080V48	4800	
DRD3080V46	4600	
DRD3080V44	4400	

Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DRD3080V48 for a 4800V device

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

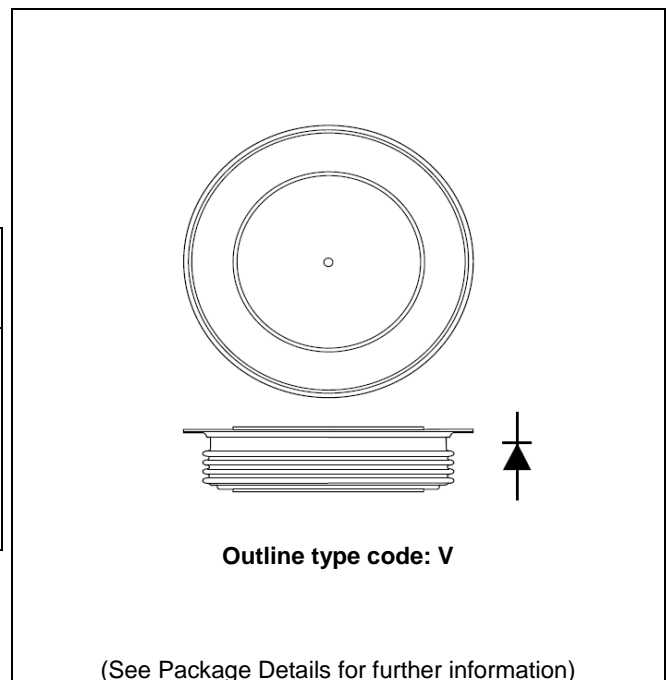


Fig. 1 Package outline

CURRENT RATINGS

T_{case} = 75°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Side Cooled				
I _{F(AV)}	Mean forward current	Half wave resistive load	3972	A
I _{F(RMS)}	RMS value	-	6239	A
I _F	Continuous (direct) on-state current	-	5973	A
Single Side Cooled (Anode side)				
I _{F(AV)}	Mean forward current	Half wave resistive load	2926	A
I _{F(RMS)}	RMS value	-	4596	A
I _F	Continuous (direct) on-state current	-	4066	A

T_{case} = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Side Cooled				
I _{F(AV)}	Mean forward current	Half wave resistive load	3083	A
I _{F(RMS)}	RMS value	-	4843	A
I _F	Continuous (direct) on-state current	-	4538	A
Single Side Cooled (Anode side)				
I _{F(AV)}	Mean forward current	Half wave resistive load	2033	A
I _{F(RMS)}	RMS value	-	3193	A
I _F	Continuous (direct) on-state current	-	2748	A

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I_{FSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 150^{\circ}C$ $V_R = 50\% V_{RRM} - 1/4$ sine	44	kA
I^2t	I^2t for fusing		9.68	MA ² s
I_{FSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 150^{\circ}C$ $V_R = 0$	55	kA
I^2t	I^2t for fusing		15.12	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	Min.	Max.	Units	
$R_{th(j-c)}$	Thermal resistance – junction to case	Double side cooled	DC	-	0.0075	$^{\circ}C/W$
		Single side cooled	Anode DC	-	0.015	$^{\circ}C/W$
			Cathode DC	-	0.015	$^{\circ}C/W$
$R_{th(c-h)}$	Thermal resistance – case to heatsink	Clamping force 43kN (with mounting compound)	Double side	-	0.002	$^{\circ}C/W$
			Single side	-	0.004	$^{\circ}C/W$
T_{vj}	Virtual junction temperature	On-state (conducting)		-	160	$^{\circ}C$
		Reverse (blocking)		-	150	$^{\circ}C$
T_{stg}	Storage temperature range			-55	150	$^{\circ}C$
F_m	Clamping force			38.0	47.0	kN

CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V _{FM}	Forward voltage	At 3000A peak, T _{case} = 25°C	-	1.25	V
I _{RM}	Peak reverse current	At V _{DRM} , T _{case} = 150°C	-	100	mA
Q _S	Total stored charge	I _F = 2000A, dI _{RR} /dt = 4A/μs	-	7500	μC
I _{rr}	Peak reverse recovery current	T _{case} = 150°C, V _R = 100V	-	190	A
V _{TO}	Threshold voltage	At T _{vj} = 150°C	-	0.82	V
r _T	Slope resistance	At T _{vj} = 150°C	-	0.143	mΩ

CURVES

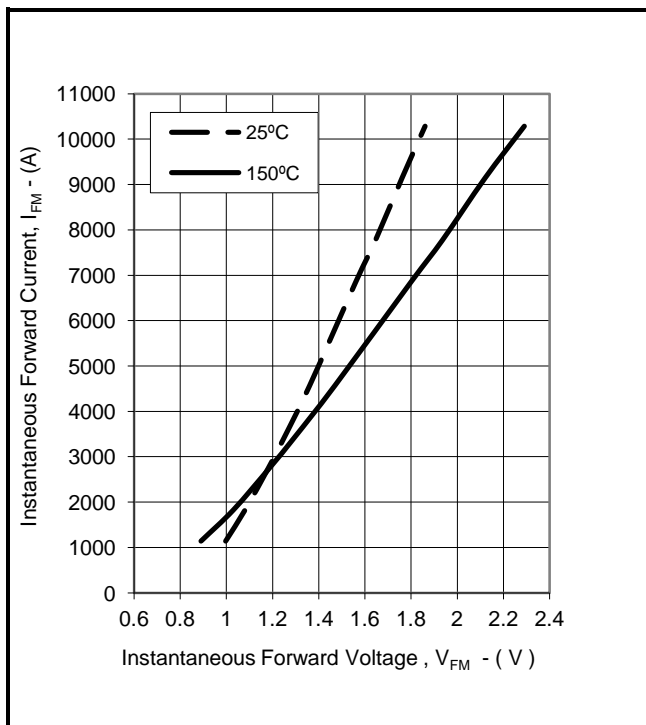


Fig.2 Maximum (limit) on-state characteristics

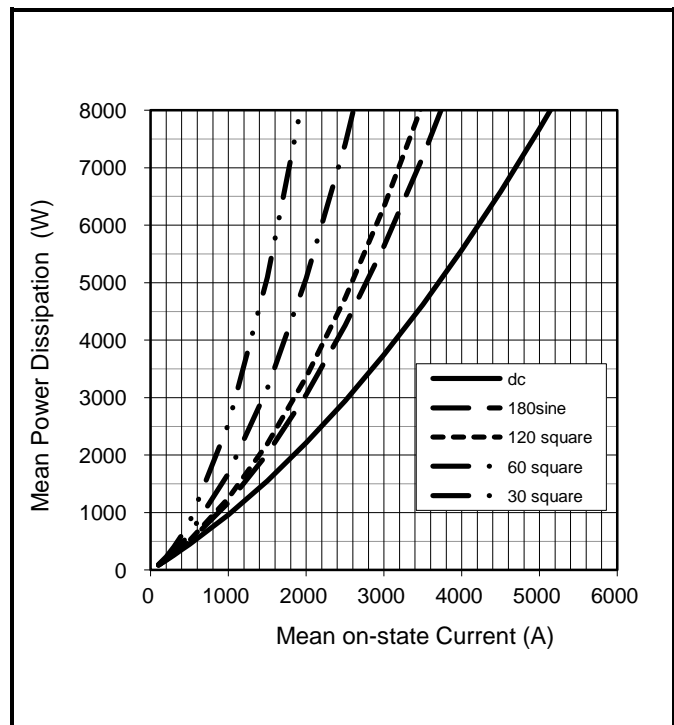


Fig.3 Dissipation curves

V_{TM} EQUATION

$$V_{TM} = A + B \ln(I_T) + C \cdot I_T + D \cdot \sqrt{I_T}$$

Where A = - 0.630059
 B = 0.2338835
 C = 0.000166
 D = - 0.009367

these values are valid for T_j = 150°C for I_F 1000A to 11000A

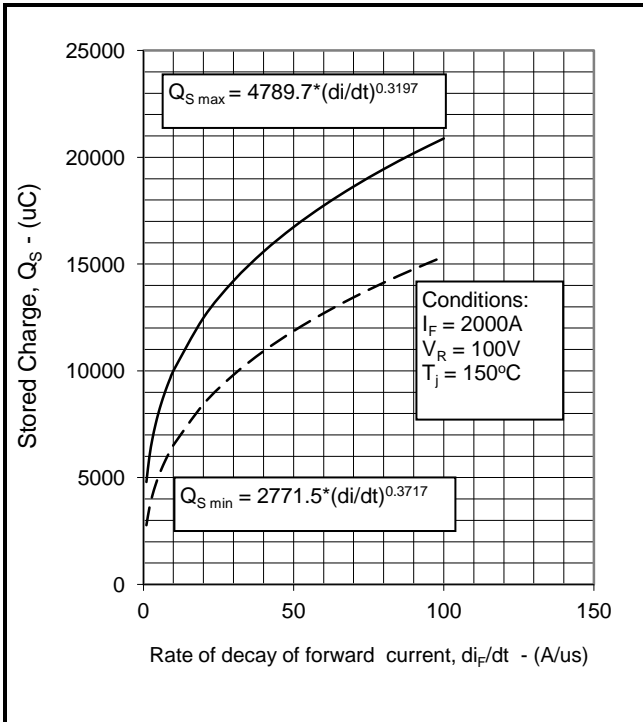


Fig.4 Total stored charge

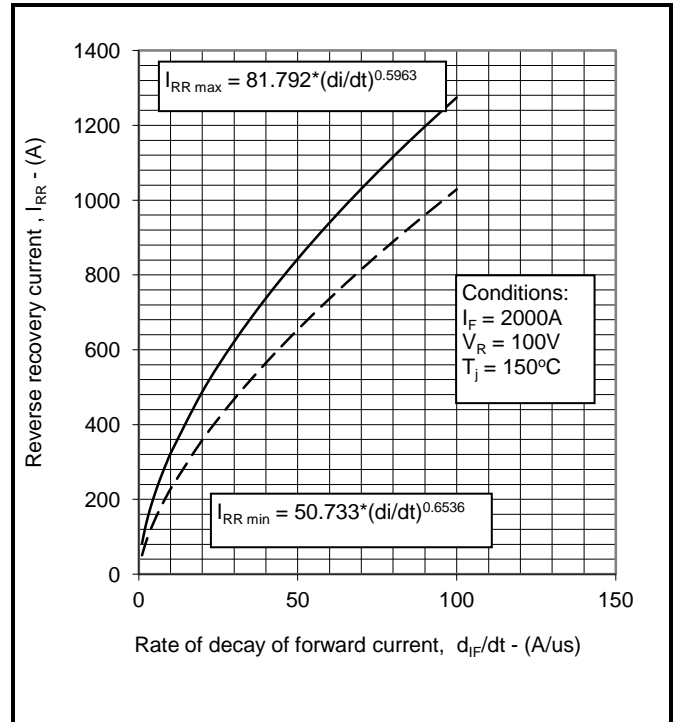


Fig.5 Maximum reverse recovery current

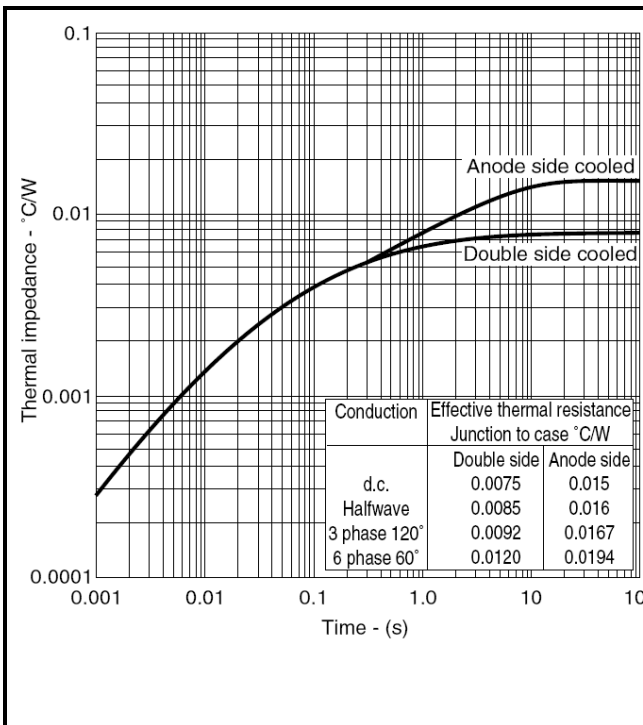
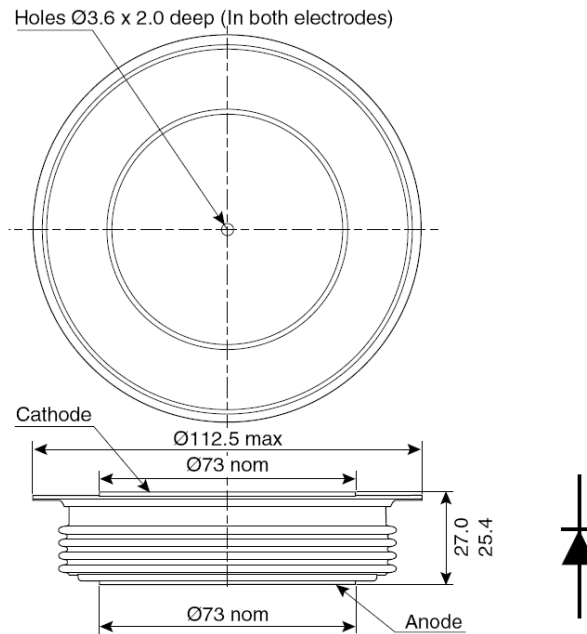


Fig.6 Maximum (limit) transient thermal impedance-junction to case

PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Normal weight: 1100g
Clamping force: $43\text{kN} \pm 10\%$

Package outline type code:V

Note:
Some packages may be supplied with gate and or tags.

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